

SuperMOS – SOT23-3L -30V V_{DSS} , $44m\Omega$ $R_{DS(on)}$, P-channel MOSFET

1. Description

The ES3401A is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product ES3401A is Pb-free.

2. Features

- -30V, $R_{DS(ON)}=44m\Omega(TYP.) @V_{GS}=-10V$
- $R_{DS(ON)}=53m\Omega(TYP.) @V_{GS}=-4.5V$
- Fast Switching
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
ES3401A	SOT23-3L	3401	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

5. Pin Configuration and Functions

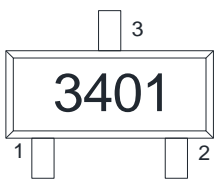
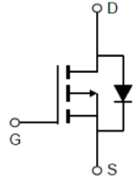
Pin	Function	Outline	Circuit Diagram
1	Gate		
2	Source		
3	Drain		

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	BV_{DSS}	-30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	-4.2
		$T_A=100^\circ\text{C}$	-3.5
Maximum Power Dissipation	P_D	$T_A=25^\circ\text{C}$	1.4
		$T_A=100^\circ\text{C}$	0.9
Pulsed Drain Current	I_{DM}	-30	A
Operating Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

Thermal resistance ratings

Single Operation			
Parameter	Symbol	Typical	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	90	$^\circ\text{C/W}$
Junction-to-Case Thermal Resistance	$R_{\theta JC}$	60	

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-24V, V_{GS}=0V$			-1	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 12V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=-250\mu A$	-0.5	-0.8	-1.1	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4A$		44	60	m Ω
		$V_{GS}=-4.5V, I_D=-3A$		53	78	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C_{ISS}	$V_{GS}=0V$ $V_{DS}=-15V$ $f=1MHz$		954		pF
Output Capacitance	C_{OSS}			115		
Reverse Transfer Capacitance	C_{RSS}			77		
Gate Resistance	R_g	$f=1MHz$		6		Ω
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS}=-4.5V$ $V_{DS}=-15V$ $I_D=-4A$		9.4		nC
Gate-to-Source Charge	Q_{GS}			2		
Gate-to-Drain Charge	Q_{GD}			3		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=-10V$ $V_{DS}=-15V$ $R_L=3.6\Omega$ $R_G=6\Omega$		6.3		ns
Rise Time	t_r			3.2		
Turn-Off Delay Time	$t_{d(OFF)}$			38.2		
Fall Time	t_f			12		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-1.0A$		-0.8	-1	V

7. Typical Characteristic

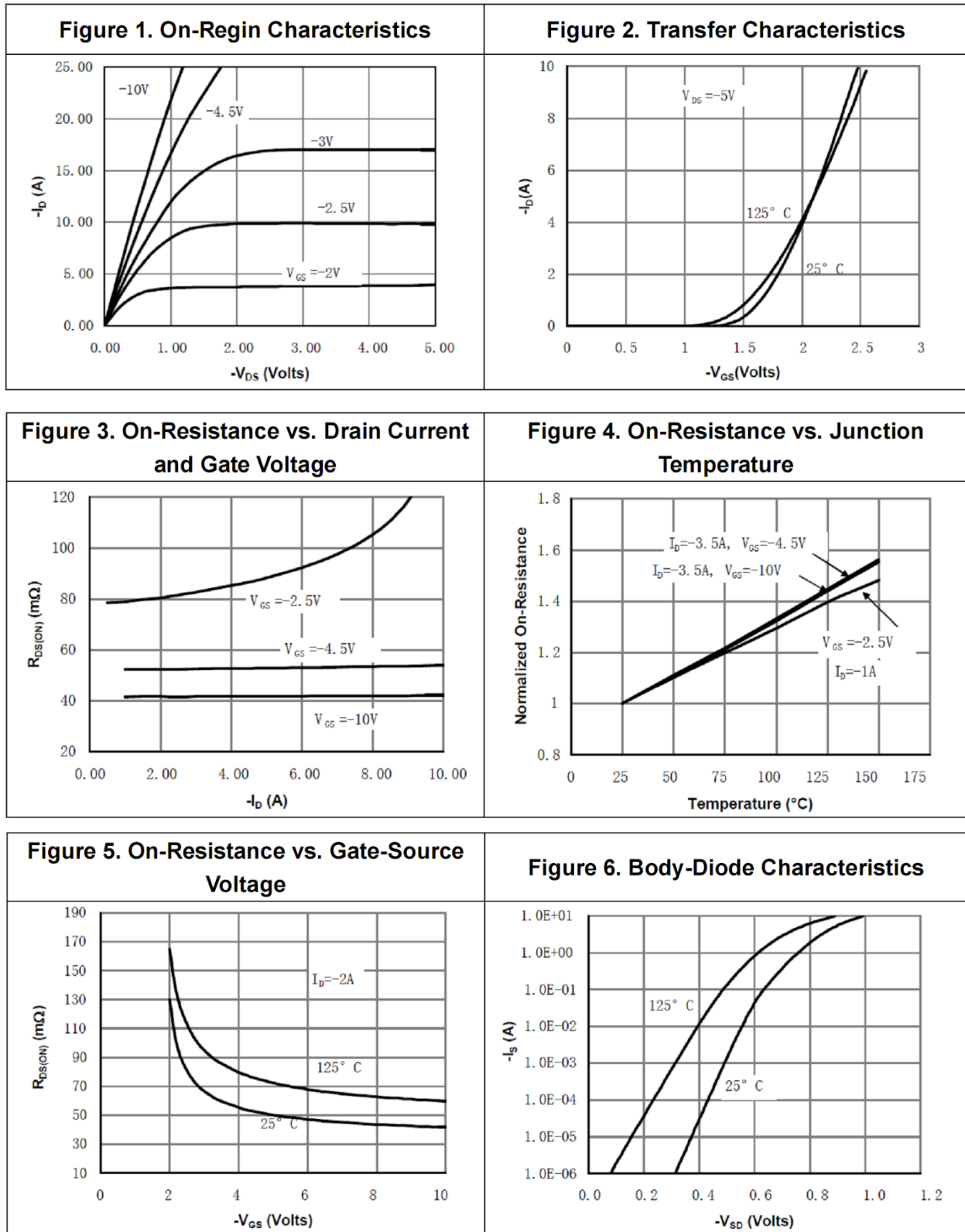


Figure 7. Gate-Charge Characteristics

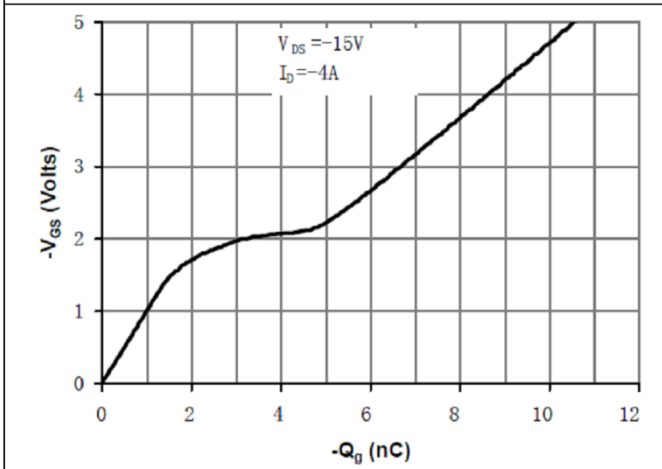


Figure 8. Capacitance Characteristics

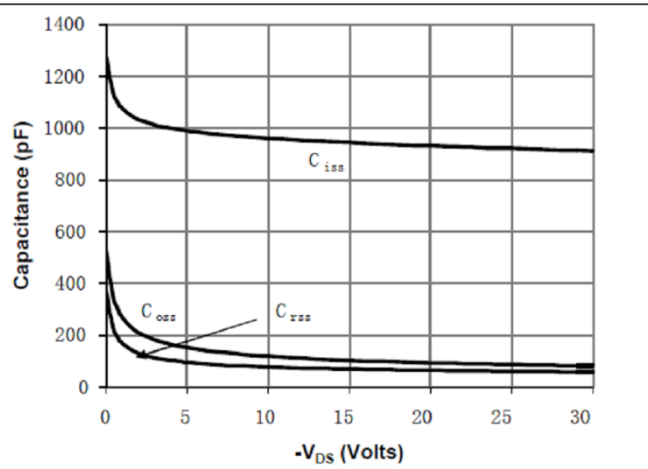


Figure 9. Maximum Forward Biased Safe Operating Area

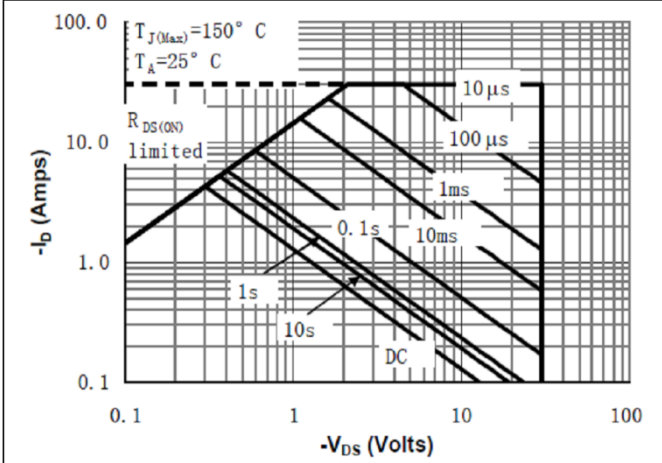


Figure 10. Single Pulse Power Rating Junction-to-Ambient

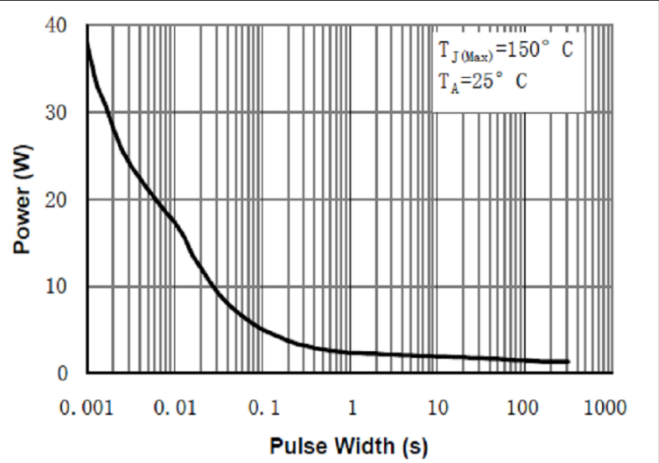
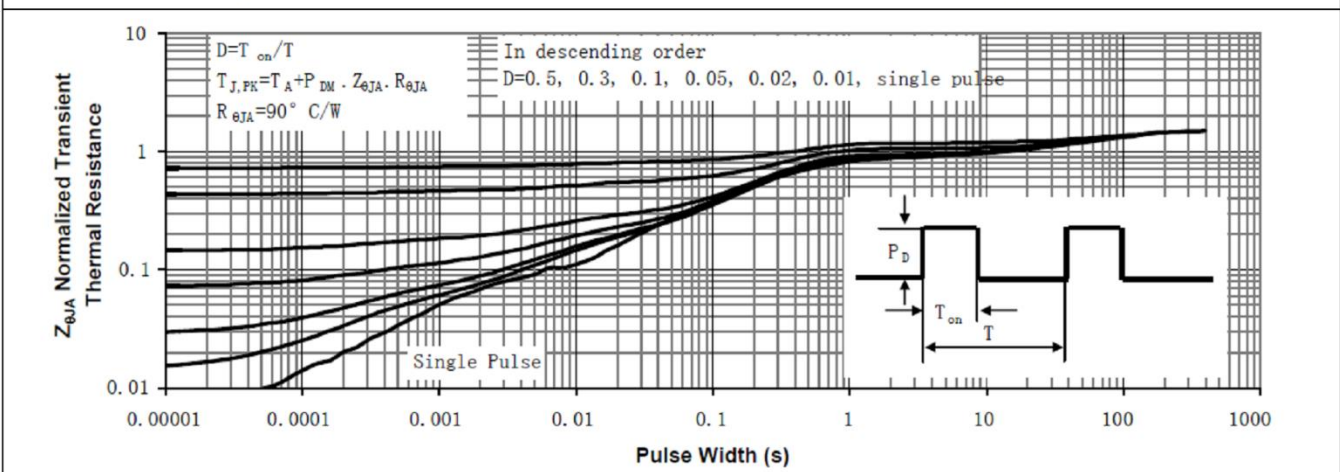
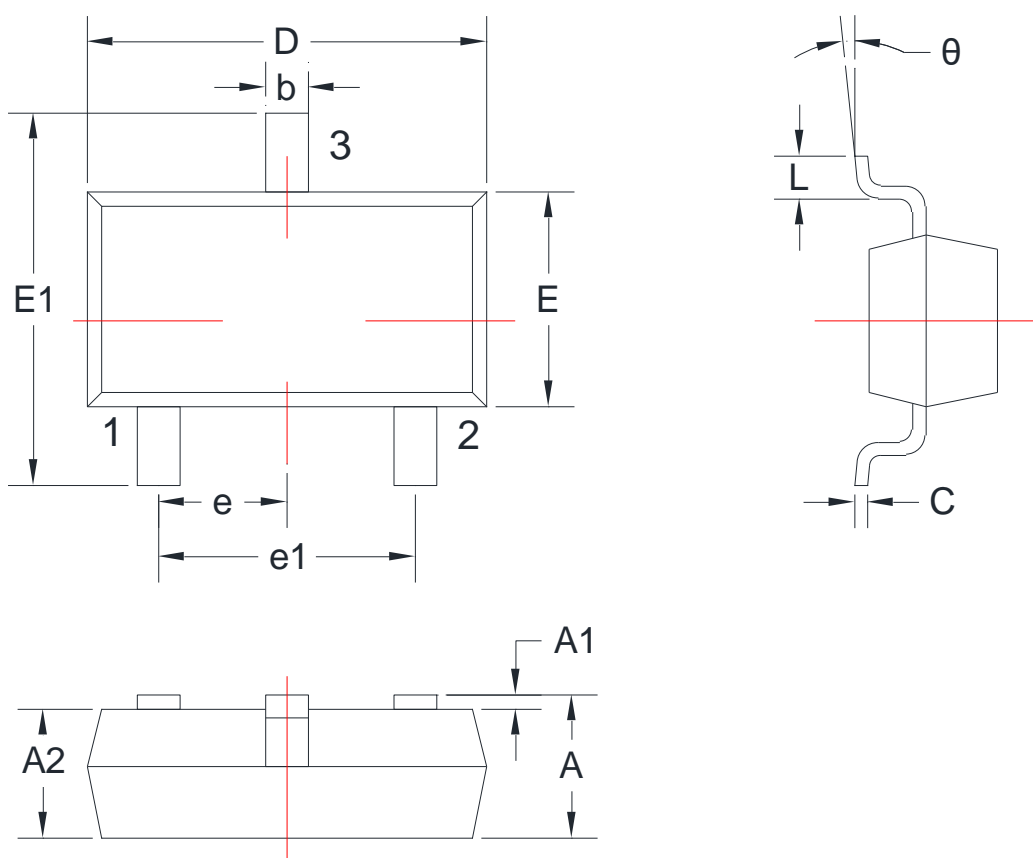


Figure 11. Normalized Maximum Transient Thermal Impedance



8. Dimension (SOT23-3L)



COMMON DIMENSIONS: UNITS OF MEASURE=MILLIMETER

Symbol	Dimensions		Symbol	Dimensions	
	Min.	Max.		Min.	Max.
A	1.05	1.25	E	1.50	1.70
A1	0	0.10	E1	2.65	2.95
A2	1.05	1.15	e	0.95TYP	
b	0.30	0.50	e1	1.80	2.00
c	0.10	0.20	L	0.30	0.60
D	2.82	3.02	θ	0°	8°

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